

## Surface Mount Attenuator 3 Watts, 3dB



### Features:

- RoHS Compliant
- 3 Watts
- Low Cost
- DC – 6.0GHz
- Al<sub>2</sub>O<sub>3</sub> Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

### Description:

The XRA3GG3SES is a high performance Alumina (Al<sub>2</sub>O<sub>3</sub>) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless communication frequency bands. The high power handling makes the part ideal for inter-stage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

### General Specifications:

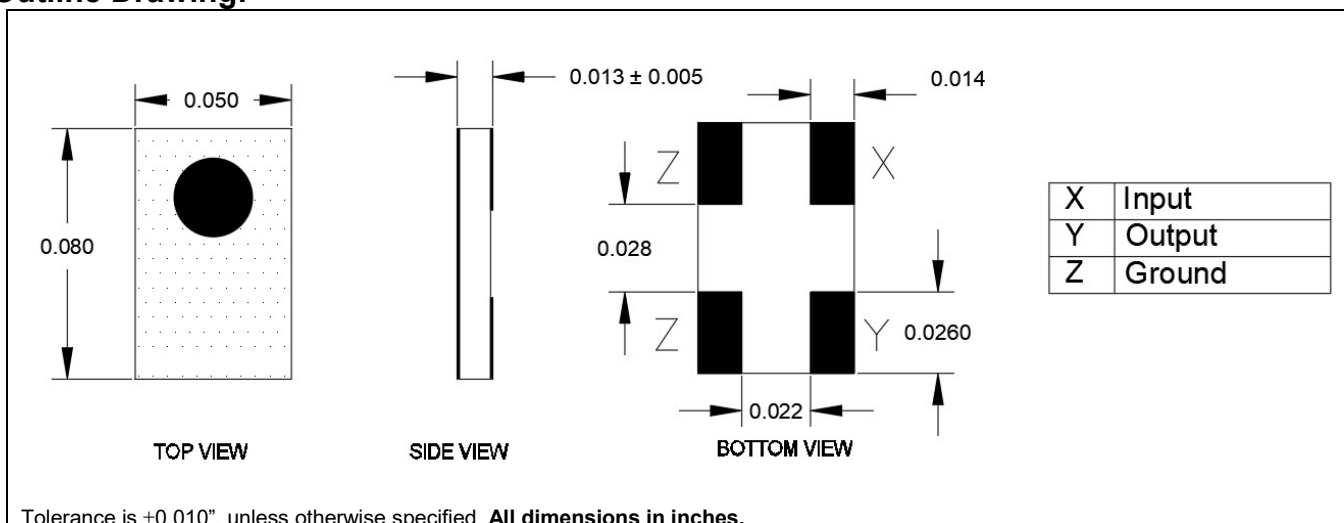
<b>Resistive Element</b>	Thick film
<b>Substrate</b>	Al <sub>2</sub> O <sub>3</sub> Ceramic
<b>Terminal Finish</b>	Matte Tin over Nickel Barrier
<b>Operating Temperature</b>	-55 to +150°C (see de-rating chart)

### Electrical Specifications:

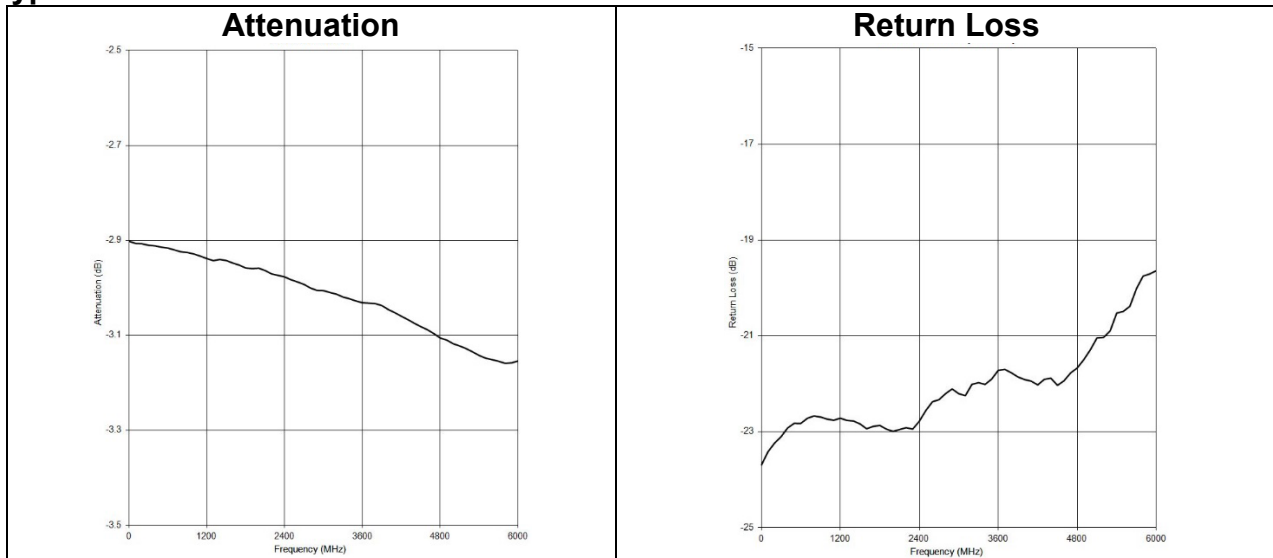
<b>Attenuation Value:</b>	3.0 ± 0.3 dB
<b>Power:</b>	3 Watts
<b>Frequency Range:</b>	DC – 6.0GHz
<b>Input Return Loss:</b>	18dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

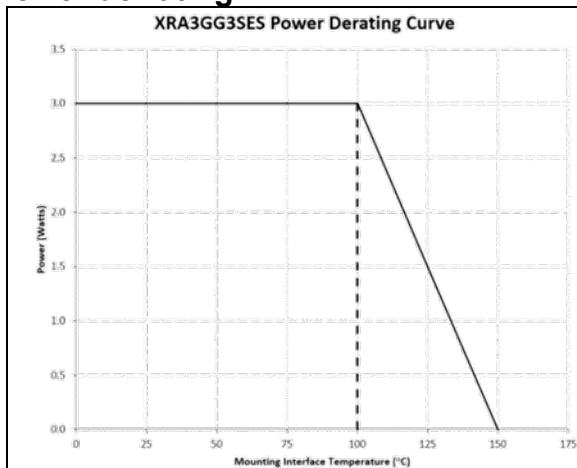
### Outline Drawing:



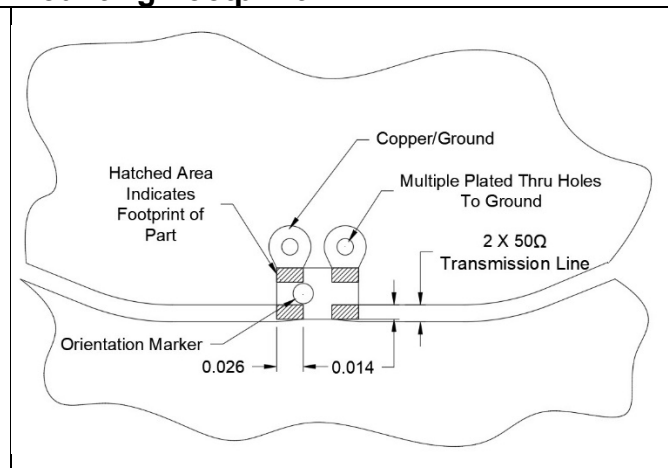
### Typical Performance:



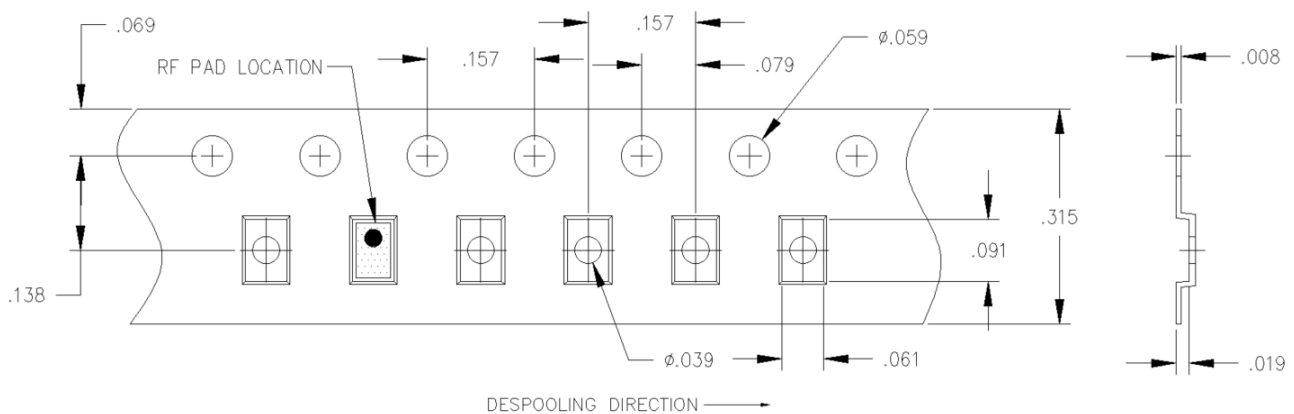
### Power de-rating:



### Mounting Footprint:



### Tape & Reel:



TAPE DETAIL & RF PAD ORIENTATION